ANALOG DEVICES

HMC1082LP4E

v01.0314

RoHS EARTH FRIENDLY

GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 5.5 - 18 GHz

Typical Applications

The HMC1082LP4E is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios
- VSAT & SATCOM
- Marine Radar
- Military EW & ECM

Features

High Saturated Output Power: 26 dBm @ 26% PAE

High Output IP3: 35 dBm

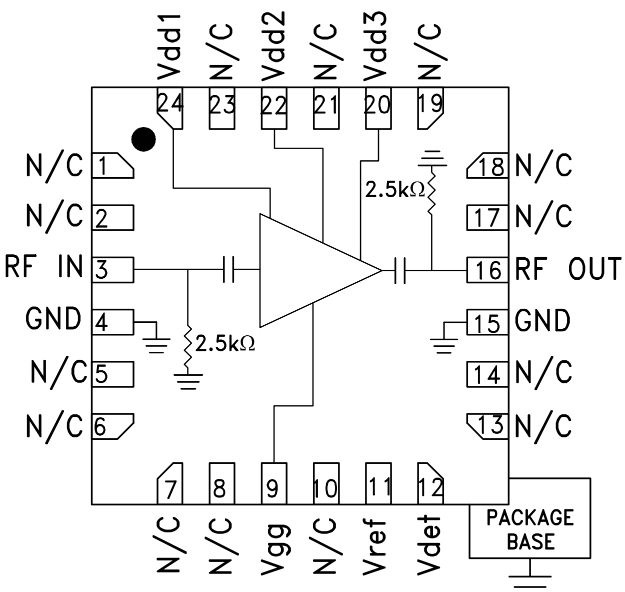
High Gain: 22 dB

High P1dB Output Power: 24 dBm

DC Supply: +5V @ 220 mA

Compact 24 Lead 4x4 mm SMT Package: 16 mm^2

Functional Diagram



General Description

The HMC1082LP4E is a GaAs pHEMT MMIC driver amplifier with an integrated temperature compensated on-chip power detector which operates between 5.5 and 18 GHz. The amplifier provides 22 dB of gain, +35 dBm Output IP3, and +24 dBm of output power at 1 dB gain compression, while requiring 220 mA from a +5V supply. The HMC1082LP4E is capable of supplying +26 dBm of saturated output power with 26 % PAE and is housed in a compact leadless 4x4 mm plastic surface mount package.

The HMC1082LP4E is an ideal driver amplifier for a wide range of applications including point-to-point radio from 5.5 to 18 GHz and marine radar at 9 GHz. The HMC1082LP4E may also be used for 6 to 18 GHz EW and ECM applications.

Electrical Specifications

T_A = +25° C, Vdd1 = Vdd2 = Vdd3 = +5V, Idd = +220 mA [1]

Parameter	Min	Typ.	Max	Min	Typ.	Max	Min	Typ	Max	Units
Frequency Range		5.5 - 6.5			6.5 - 17			17 - 18		GHz
Gain	21.5	23.5		20.5	22.5		20	22		dB
Gain Variation over temperature		0.0121			0.0101			0.015		dB/°C
Input Return Loss		22			12			7.5		dBm
Output Return Loss		10			14			17.5		dBm
Output Power for 1 dB Compression (P1dB)	21	24		21	24		20.5	23.5		dBm
Saturated Output Power (Psat)		25.5			26			24.5		dBm
Output Third Order Intercept (IP3) [2]		36			35			33.5		dBm
Supply Current (Idd)		220			220			220		mA

[1] Adjust Vgg between -2 to 0V to achieve Idd = 220mA typical

[2] Measurement taken at Pout / tone = +12dBm

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HMC1082* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- HMC1082LP4 Evaluation Board

DOCUMENTATION

Application Notes

- AN-1363: Meeting Biasing Requirements of Externally Biased RF/Microwave Amplifiers with Active Bias Controllers
- Broadband Biasing of Amplifiers General Application Note
- MMIC Amplifier Biasing Procedure Application Note
- Thermal Management for Surface Mount Components General Application Note

Data Sheet

- HMC1082 Data Sheet

TOOLS AND SIMULATIONS

- HMC1082 S-Parameters

REFERENCE MATERIALS

Quality Documentation

- Package/Assembly Qualification Test Report: LP3, LP4, LP5 & LP5G (QTR: 2014-00145)
- Semiconductor Qualification Test Report: PHEMT-F (QTR: 2013-00269)

DESIGN RESOURCES

- HMC1082 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC1082 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

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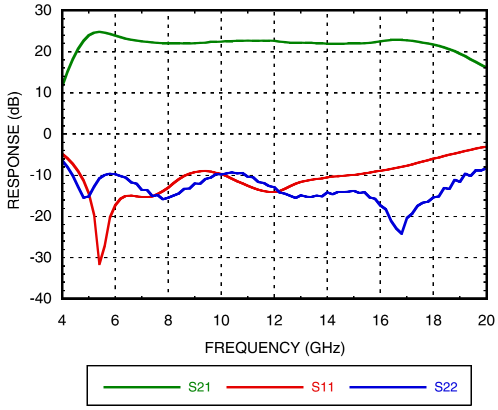
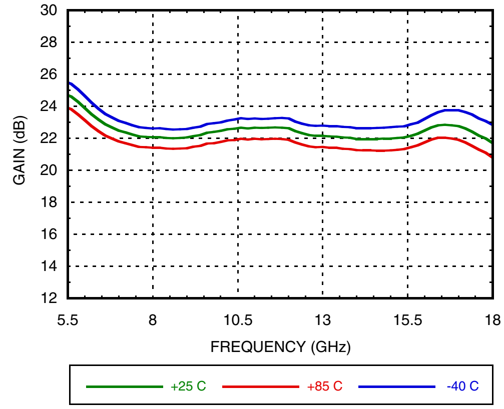
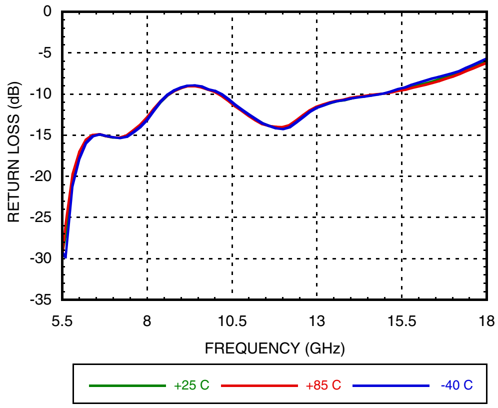
Broadband Gain & Return Loss



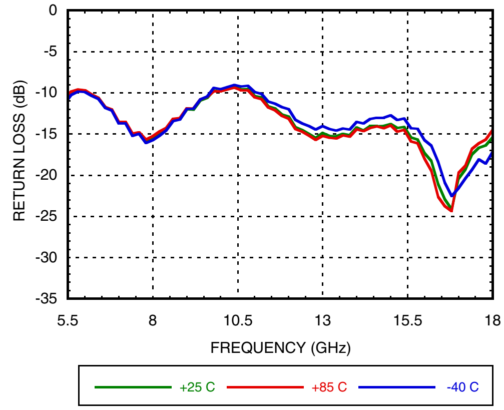
Gain vs. Temperature



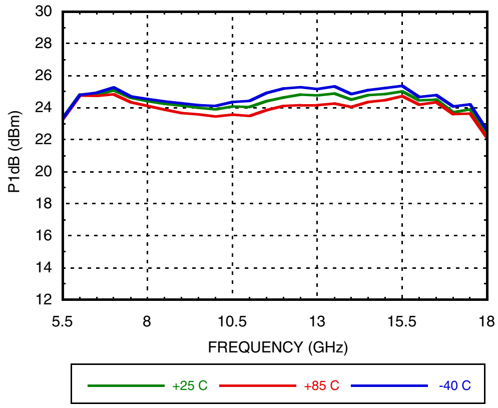
Input Return Loss vs. Temperature



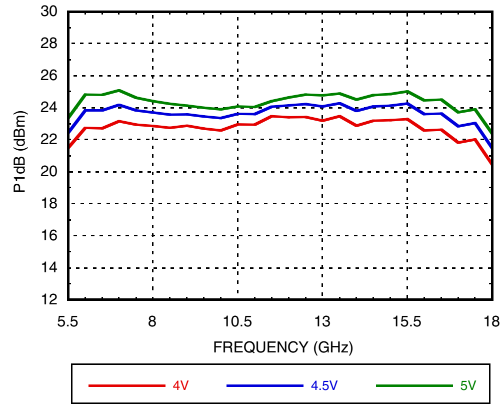
Output Return Loss vs. Temperature



P1dB vs. Temperature



P1dB vs. Supply Voltage



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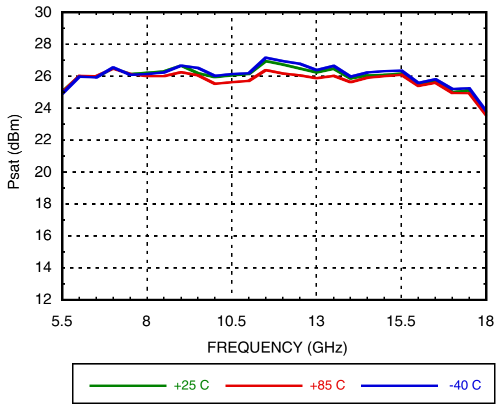
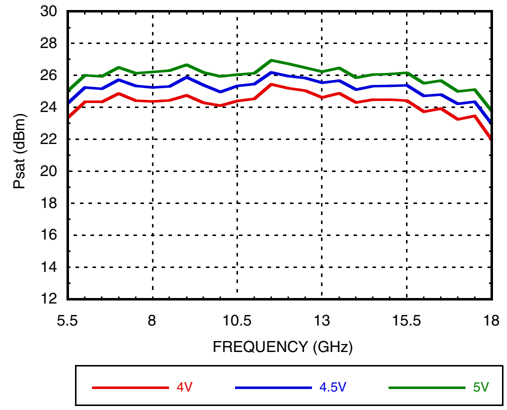
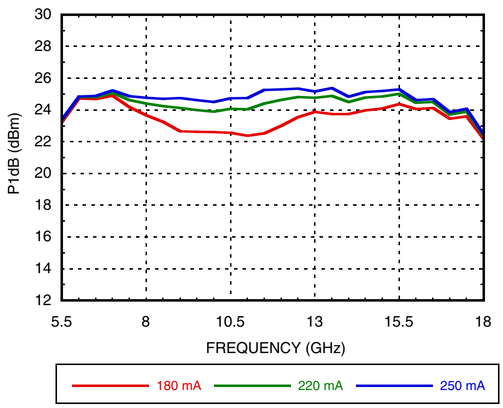
Psat vs. Temperature



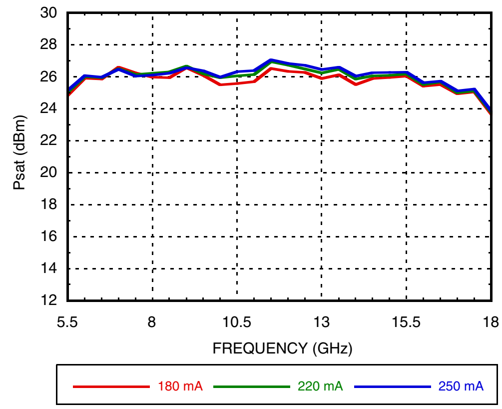
Psat vs. Supply Voltage



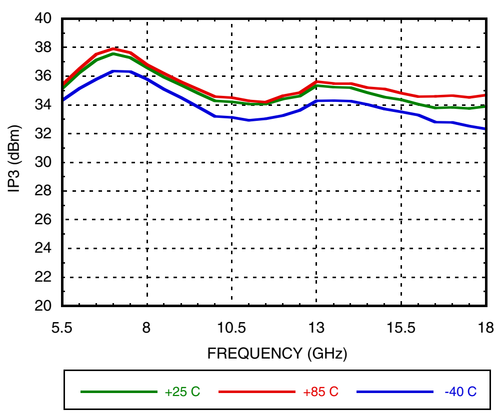
P1dB vs. Supply Current



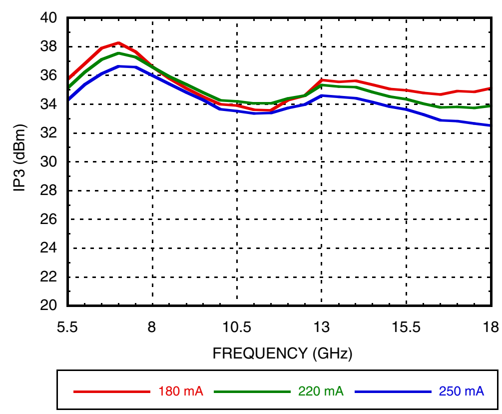
Psat vs. Supply Current



Output IP3 vs. Temperature [1]



Output IP3 vs. Supply Current [1]



[1] Pout/Tone = +12 dBm

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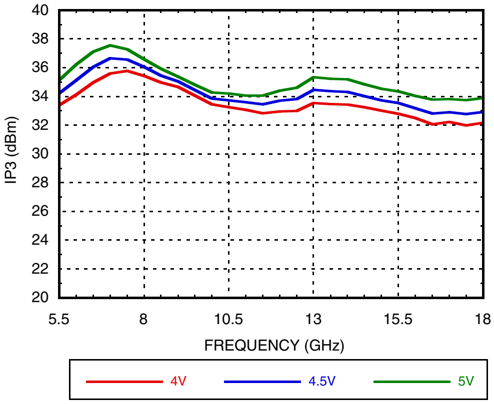
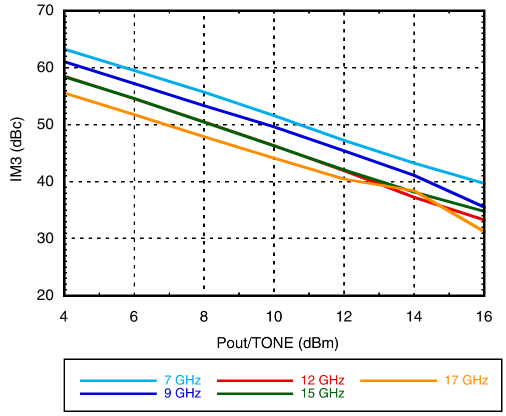
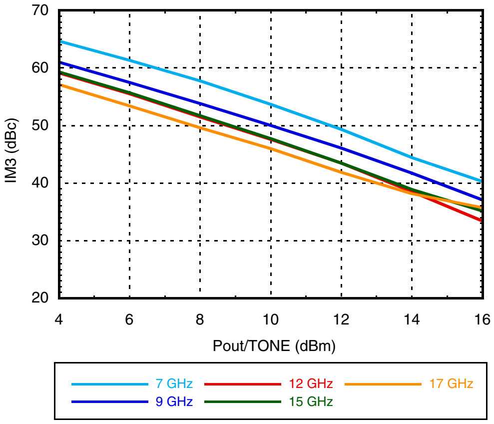
Output IP3 vs. Supply Voltage [1]



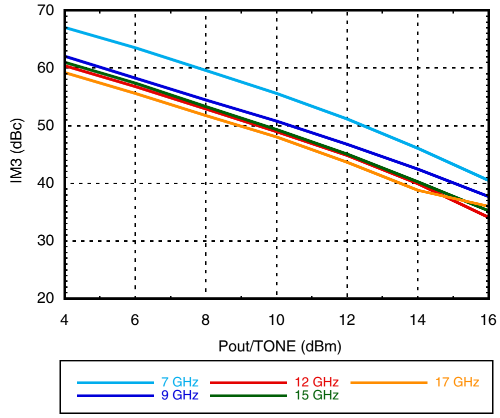
Output IM3 @ Vdd = +4V



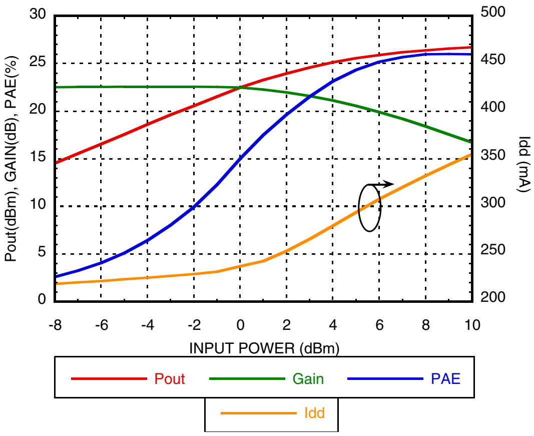
Output IM3 @ Vdd = +4.5V



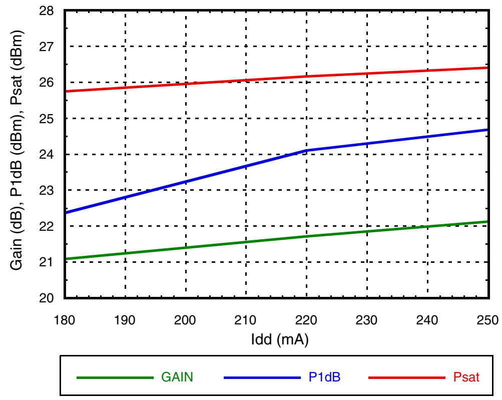
Output IM3 @ Vdd = +5V



Power Compression @ 12 GHz



Gain & Power vs. Supply Current



[1] Pout/Tone = +12 dBm

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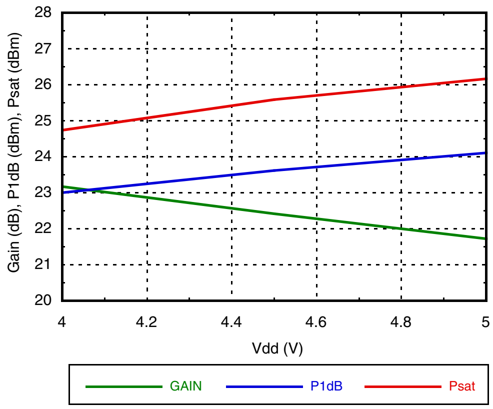
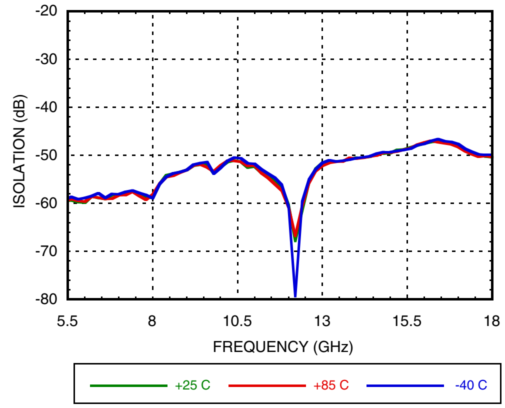
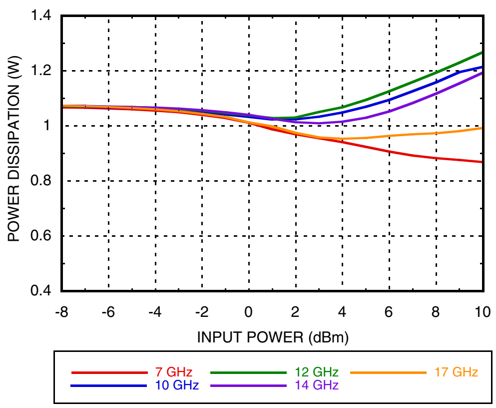
Gain & Power vs. Supply Voltage



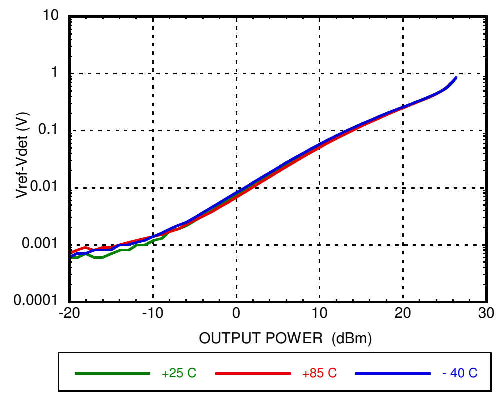
Reverse Isolation vs. Temperature



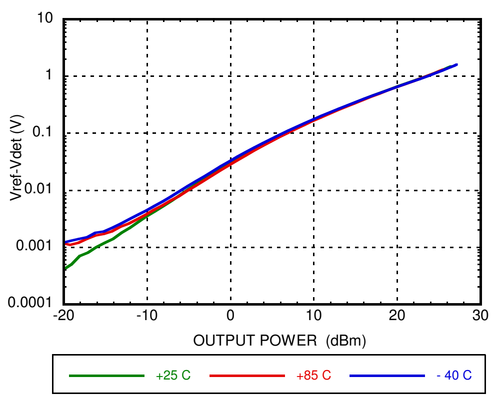
Power Dissipation



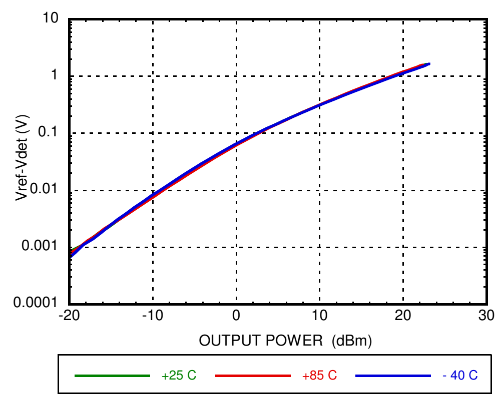
Detector Voltage vs. Temperature @ 6 GHz



Detector Voltage vs. Temperature @ 12 GHz



Detector Voltage vs. Temperature @ 18 GHz



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Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	5.5V
RF Input Power (RFIN)	20 dBm
Channel Temperature	175 °C
Continuous Pdiss (T=85 °C) (derate 20mW/°C	1.81W
Thermal Resistance (R_{TH}) (junction to ground paddle)	49.8 °C/W
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to 150°C
ESD Sensitivity (HBM)	Class 0, Passed 100V

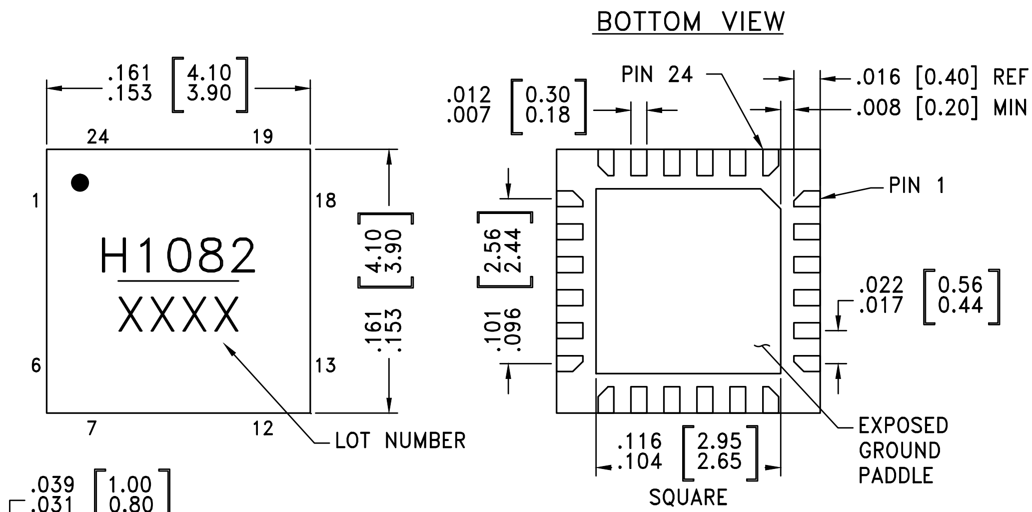
Typical Supply Current vs. Vdd

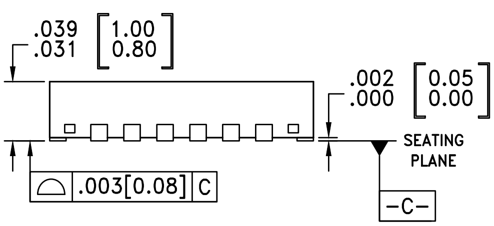
Vdd (V)	Idd (mA)
+4	220
+4.5	220
+5	220

Adjust Vgg1 to achieve Idd = 220mA

ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing





NOTES:
1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS].
3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED PCB LAND PATTERN.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating [2]	Package Marking [1]
HMC1082LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1	H1082 XXXX

[1] 4-Digit lot number XXXX
[2] Max peak reflow temperature of 260 °C

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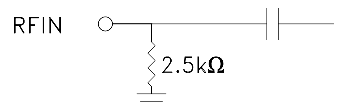
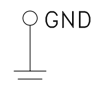
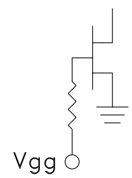
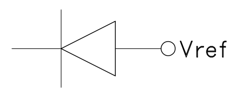
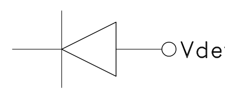
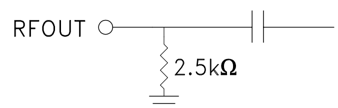
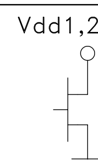
Pin Descriptions

Pin Number	Function	Description	Pin Schematic
1, 2, 5, 6, 7, 8, 10, 13, 14, 17, 18, 19, 21, 23	N/C	These pins are not connected internally, however all data shown herein was measured with these pins connected to RF/DC ground externally.	
3	RF IN	This pin is DC coupled and matched to 50 Ohms.	
4, 15	GND	These pins and package bottom must be connected to RF/DC ground.	
9	Vgg	Gate control for amplifier. External bypass capacitors of 1000pF, 100pF and 2.2uF are required.	
11	Vref	DC bias of diode biased through external resistor used for temperature compensation of Vdet. See application circuit.	
12	Vdet	DC voltage representing RF output power rectified by diode which is biased through an external resistor. See application circuit.	
16	RF OUT	This pin is DC coupled and matched to 50 Ohms.	
24, 22, 20	Vdd1, Vdd2, Vdd3	Drain bias voltage for amplifier. External bypass capacitors of 1000pF, 100pF and 2.2uF are required.	

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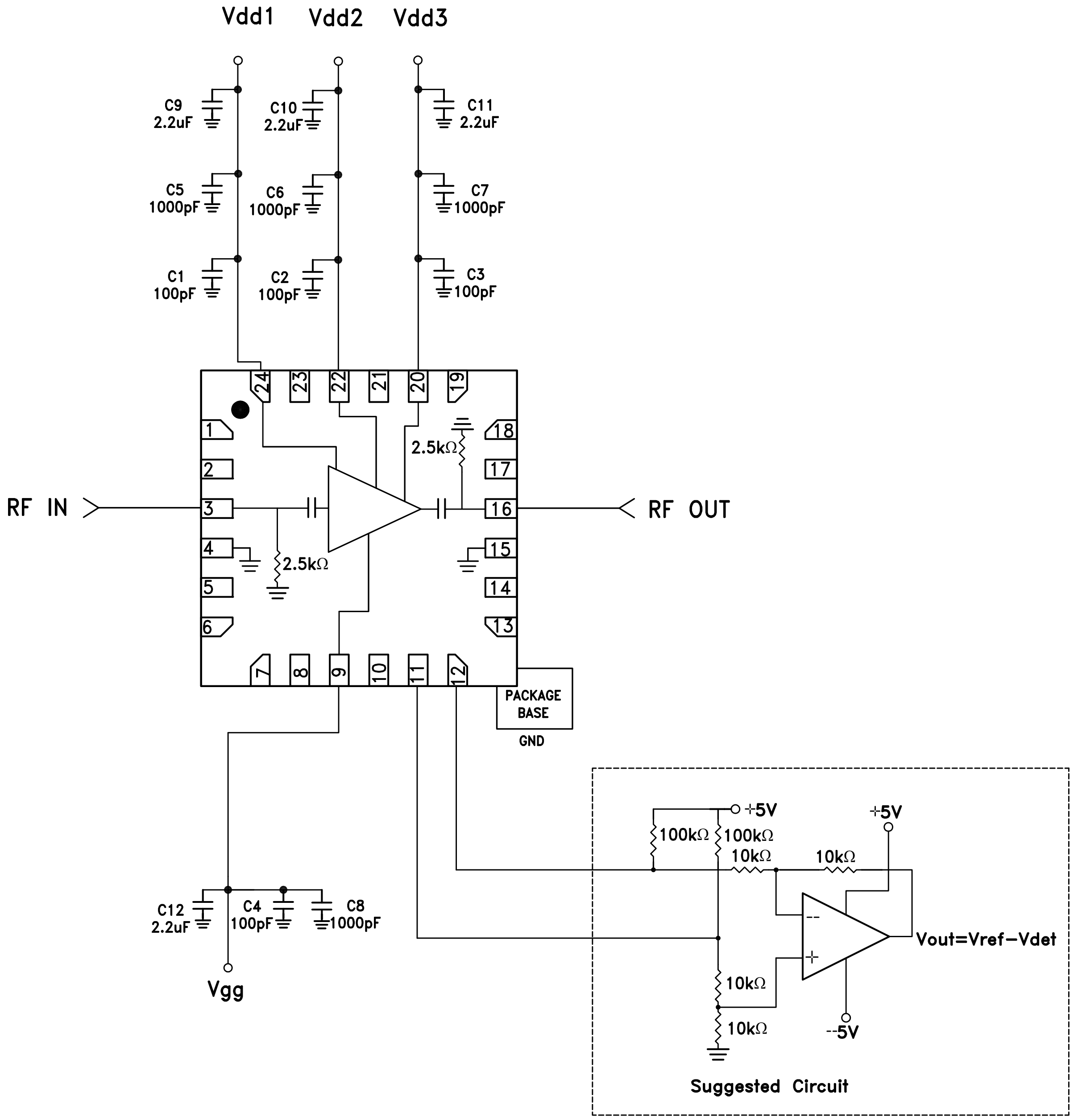
Application Circuit



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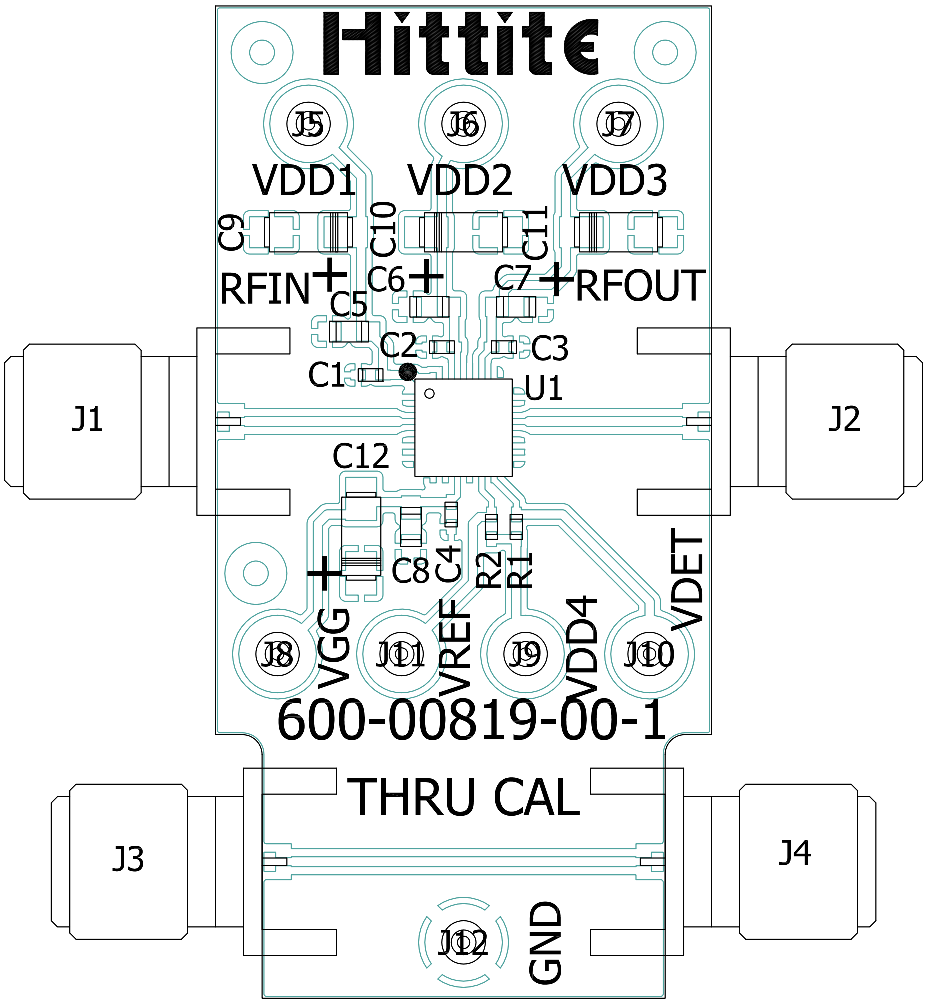
Evaluation PCB



List of Materials for Evaluation PCB EV1HMC1082LP4 [1]

Item	Description
J1, J2	PCB Mount SMA RF Connector
J5 - J12	DC Pin
C1 - C4	100pF Capacitor, 0402 Pkg.
C5 - C8	1000pF Capacitor, 0402 Pkg
C9 - C12	2.2uF Capacitor, 0402 Pkg.
R1, R2	40.2k Ohm Resistor, 0402 Pkg.
U1	HMC1082LP4E
PCB [2]	600-00819-00 Evaluation Board

[1] Reference this number when ordering Complete Evaluation PCB

[2] Circuit Board Material: Rogers 4350 or Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

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